



SS32B THRU SS3200B

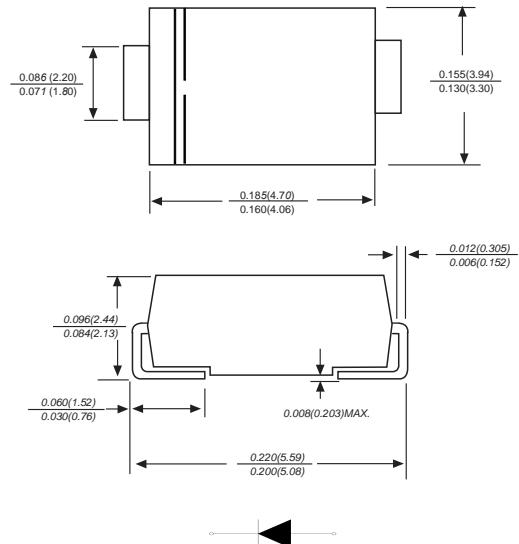
Reverse Voltage - 20 to 200 Volts Forward Current - 3.0 Ampere

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction,majority carrier conduction
- ◆ Low power loss,high efficiency
- ◆ Built-in strain relief,ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250 °C/10 seconds at terminals

DO-214AA/SMB



Dimensions in inches and (millimeters)

Mechanical Data

Case : JEDEC DO-214AA/SMB molded plastic body
 Terminals : Solderable per MIL-STD-750, Method 2026
 Polarity : Color band denotes cathode end
 Mounting Position : Any
 Weight : 0.003 ounce, 0.095 grams

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

| Parameter | SYMBOLS | MDD SS32B | MDD SS33B | MDD SS34B | MDD SS35B | MDD SS36B | MDD SS38B | MDD SS310B | MDD SS3150B | MDD SS3200B | UNITS |
|--|-------------------|-----------|-----------|-----------|-------------|-----------|-----------|------------|-------------|-------------|-------|
| Marking Code | | | | | | | | | | | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | 150 | 200 | V |
| Maximum RMS voltage | V _{RMS} | 14 | 21 | 28 | 35 | 42 | 56 | 70 | 105 | 140 | V |
| Maximum DC blocking voltage | V _{DC} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | 150 | 200 | V |
| Maximum average forward rectified current | I _(AV) | | | | | | | 3 | | | A |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I _{FSM} | | | | | | | 80 | | | A |
| Maximum instantaneous forward voltage at 3.0A | V _F | | 0.55 | | 0.7 | | 0.85 | | 0.95 | | V |
| Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=100°C | I _R | | | 0.5 | | | | 0.3 | | | mA |
| Typical junction capacitance (NOTE 1) | C _J | | 450 | | | | 400 | | | | pF |
| Typical thermal resistance (NOTE 2) | R _{θJA} | | | | 60 | | | | | | °C/W |
| Operating junction temperature range | T _J | | | | -55 to +150 | | | | | | °C |
| Storage temperature range | T _{STG} | | | | -55 to +150 | | | | | | °C |

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 2.P.C.B. mounted with 2.0"x2.0"(5.0x5.0cm) copper pad areas



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Typical Characteristics

Fig.1 Forward Current Derating Curve

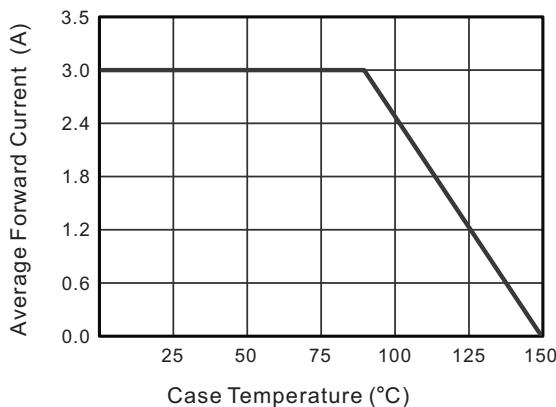


Fig.2 Typical Reverse Characteristics

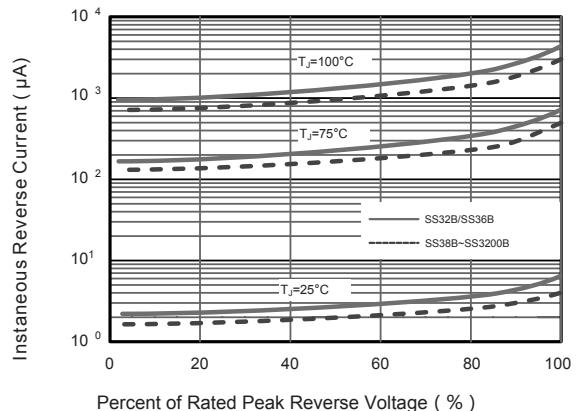


Fig.3 Typical Forward Characteristic

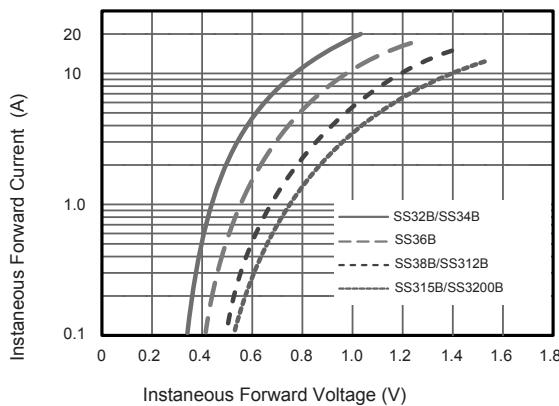


Fig.4 Typical Junction Capacitance

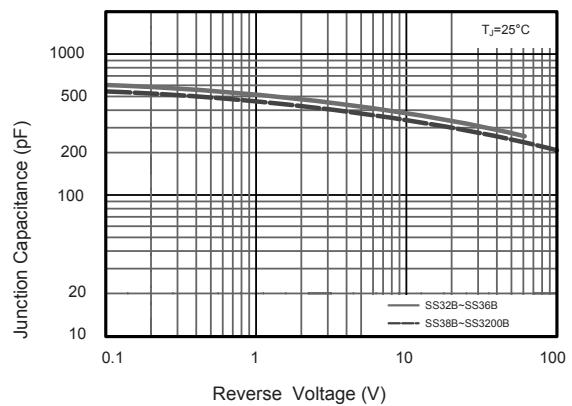


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

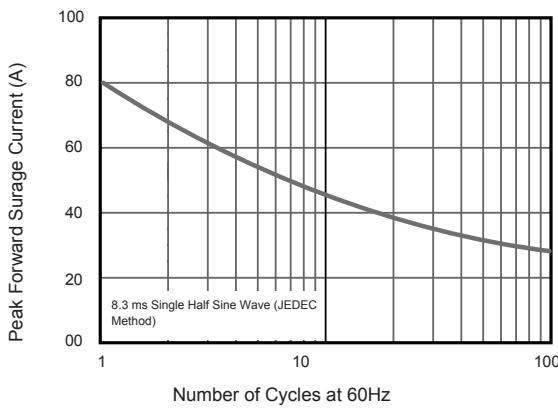
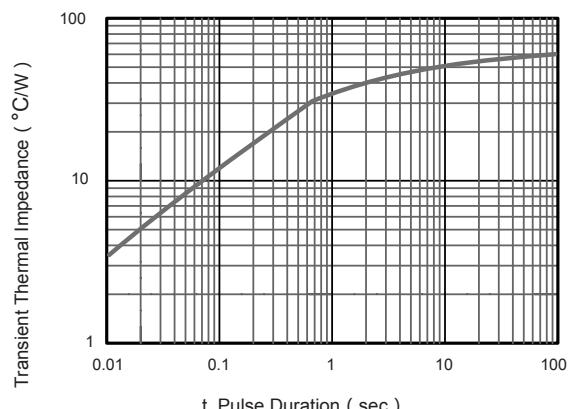


Fig.6- Typical Transient Thermal Impedance



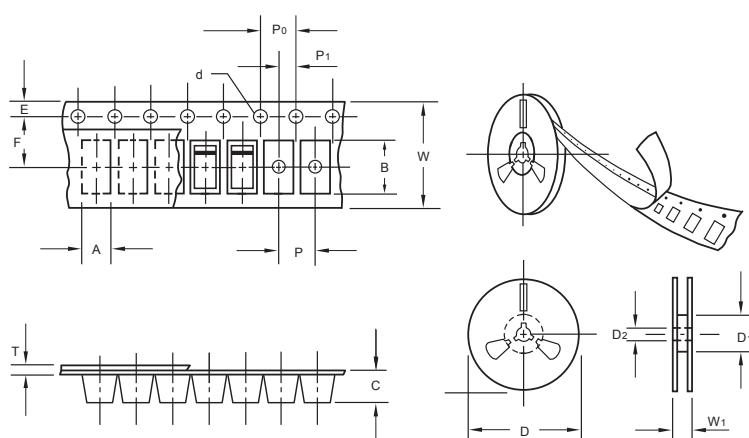
The curve above is for reference only.



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Packing information



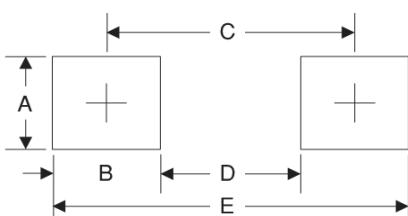
| Item | Symbol | Tolerance | SMB |
|---------------------------|--------|-----------|--------|
| Carrier width | A | 0.1 | 3.81 |
| Carrier length | B | 0.1 | 5.41 |
| Carrier depth | C | 0.1 | 2.42 |
| Sprocket hole | d | 0.05 | 1.50 |
| 13" Reel outside diameter | D | 2.0 | 330.00 |
| 13" Reel inner diameter | D1 | min | 50.00 |
| Feed hole diameter | D2 | 0.5 | 13.00 |
| Sprocket hole position | E | 0.1 | 1.75 |
| Punch hole position | F | 0.1 | 5.55 |
| Punch hole pitch | P | 0.1 | 8.00 |
| Sprocket hole pitch | P0 | 0.1 | 4.00 |
| Embossment center | P1 | 0.1 | 2.00 |
| Overall tape thickness | T | 0.1 | 0.30 |
| Tape width | W | 0.3 | 12.00 |
| Reel width | W1 | 1.0 | 12.30 |

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

Reel packing

| PACKAGE | REEL SIZE | REEL (pcs) | COMPONENT SPACING (mm) | BOX (pcs) | INNER BOX (mm) | REEL DIA, (mm) | CARTON SIZE (mm) | CARTON (pcs) | APPROX. GROSS WEIGHT (kg) |
|---------|-----------|------------|------------------------|-----------|----------------|----------------|------------------|--------------|---------------------------|
| SMB | 13" | 3,000 | 4.0 | 6,000 | 190*190*41 | 330 | 365*365*360 | 48,000 | 14.0 |

Suggested Pad Layout



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| A | 2.8 | 0.110 |
| B | 2.4 | 0.094 |
| C | 4.6 | 0.181 |
| D | 2.2 | 0.086 |
| E | 7.0 | 0.276 |

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